

2MBI1400VXB-120P-54

IGBT Modules

IGBT MODULE (V series) 1200V / 1400A / 2 in one package

■ Features

High speed switching Voltage drive Low Inductance module structure

Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines



Maximum Ratings and Characteristics

Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items	Symbols	Conditions	·	Maximum ratings	Units	
Collector-Emitter voltage	Vces			1200	V	
Gate-Emitter voltage	V _{GES}			±20	V	
	Ic	Continuous	Tc=25°C	1800		
ž		Continuous	Tc=100°C	1400		
Collector current	Ic pulse	1ms		2800	Α	
드	-lc			1400		
	-lc pulse	1ms		2800		
Collector power dissipation	Pc	1 device		7650	W	
Junction temperature	Tj			175		
Operating junction temperature (under switching conditions)	Tjop			150	°C	
Case temperature	Tc			150	C	
Storage temperature	Tstg			-40 ~ +150		
Isolation voltage between terminal and copper base (*1)	V _{iso}	AC : 1min.		4000	VAC	
between thermistor and others (*2)	V iso	AC . IIIIII.		4000	VAC	
Mounting		M5		6.0		
Screw torque (*3) Main Terminals]-	M8		10.0	N m	
Sense Terminals		M4		2.1		

Note *1: All terminals should be connected together during the test.

Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note *3: Recommendable Value: Mounting 3.0 ~ 6.0 Nm (M5)

Recommendable Value: Main Terminals 8.0 ~ 10.0 Nm (M8)

1

Recommendable Value: Sense Terminals 1.8 ~ 2.1 Nm

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

Items		Symbolo	Conditions		Ch	aracterist	ics	Units
		Symbols	Conditions	min.	typ.	max.	Units	
	Zero gate voltage collector current	Ices	$V_{GE} = 0V, V_{CE} = 1200V$		-	-	12.0	mA
	Gate-Emitter leakage current	Iges	$V_{CE} = 0V$, $V_{GE} = \pm 20V$		-	-	2400	nA
	Gate-Emitter threshold voltage	V _{GE (th)}	V _{CE} = 20V, I _C = 1400mA		6.0	6.5	7.0	V
		V _{CE (sat)}		Tj=25°C	-	1.75	2.20	
	Collector-Emitter saturation voltage (with V _{CE(sat)} classification : *5)	(terminal)		Tj=125°C	-	2.10	-	
		(*4)	V _{GE} = 15V	Tj=150°C	-	2.15	-	V
		.,	Ic = 1400A	Tj=25°C	-	1.65	2.10	- V
		V _{CE (sat)}		Tj=125°C	-	2.00	-	
		(chip)		Tj=150°C	-	2.05	-	
	Internal gate resistance	R _{g(int)}	-		-	0.79	-	Ω
ē	Input capacitance	Cies	V _{CE} = 10V, V _{GE} = 0V, f = 1MI	Hz	-	128	-	nF
nverte		ton	V _{CC} = 600V		-	1000	-	
2	Turn-on time	tr	Ic = 1400A		-	400	-	
_		tr (i)	V _{GE} = ±15V		-	150	-	nsec
	Town off the c	toff	R _G = 1Ω		-	1200	-	1
	Turn-off time	tf	Ls = 60nH	-	150	-	1	
		VF		Tj=25°C	-	1.90	2.35	
		(terminal)		Tj=125°C	-	2.05	-	1
	(with V _F classification : *5)	(*4)	$V_{GE} = 0V$	Tj=150°C	-	2.00	-	1 .,
		V.	I _F = 1400A	Tj=25°C	-	1.80	2.25	V
				Ti=125°C	-	1.95	-	1
		(chip)		Tj=150°C	-	1.90	-	1
	Reverse recovery time	trr	I _F = 1400A	•	-	200	-	nsec
Thermistor	Daniston		T=25°C		-	5000	-	Ω
rm:	Resistance	R	T=100°C)°C		495	520	$\frac{1}{\Omega}$
른	B value	В	T=25/50°C		3305	3375	3450	K

Note *4: Please refer to page 7 , there is definition of on-state voltage at terminal.

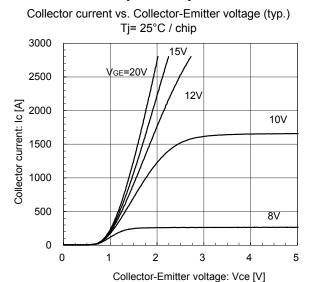
● Thermal resistance characteristics

Items	Symbols	Conditions	Ch	aracterist	ics	Units
	Symbols		min.	typ.	max.	Units
Thermal resistance (1device)	Dth/i o)	Inverter IGBT		0.0195		
	Rth(j-c)	Inverter FWD	-	-	0.0360	°C/W
Contact thermal resistance (1device) (*5)	Rth(c-f)	with Thermal Compound	•	0.00420	-	

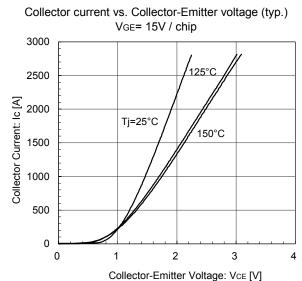
Note \star 5: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)



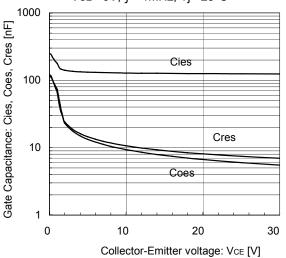


[INVERTER]

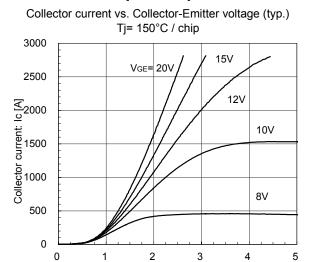


[INVERTER]

Gate Capacitance vs. Collector-Emitter Voltage (typ.) VGE=0V, f=1MHz, Tj=25°C



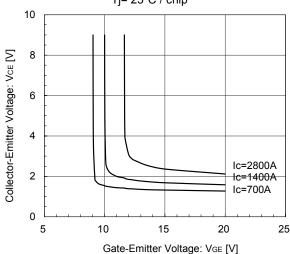
[INVERTER]



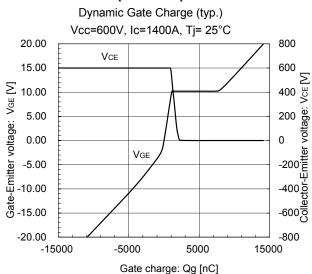
[INVERTER]

Collector-Emitter voltage: Vce [V]

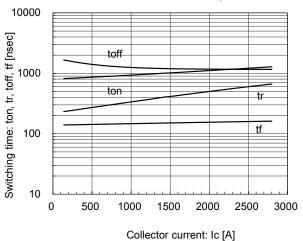
Collector-Emitter voltage vs. Gate-Emitter voltage (typ.) Tj= 25° C / chip



[INVERTER]

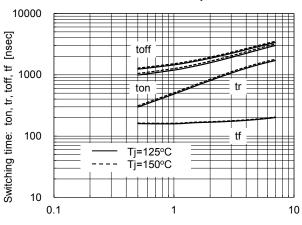


[INVERTER] Switching time vs. Collector current (typ.) Vcc=600V, $VgE=\pm15V$, $Rg=1\Omega$, $Tj=25^{\circ}C$



[INVERTER]

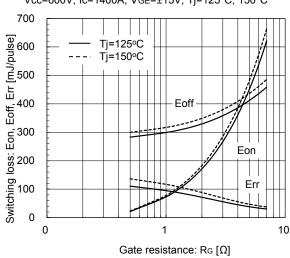
Switching time vs. Gate resistance (typ.) Vcc=600V, Ic=1400A, VGE=±15V, Tj=125°C, 150°C



Gate resistance: R_G [Ω]

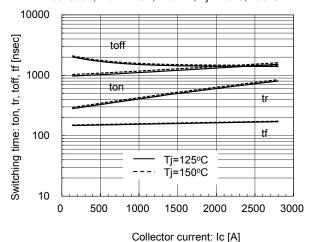
[INVERTER]

Switching loss vs. Gate resistance (typ.) Vcc=600V, Ic=1400A, VgE=±15V, Tj=125°C, 150°C



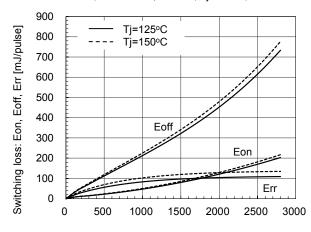
[INVERTER]

Switching time vs. Collector current (typ.) Vcc=600V, $VgE=\pm15V$, $Rg=1\Omega$, $Tj=125^{\circ}C$, $150^{\circ}C$



[INVERTER]

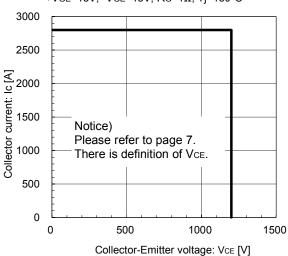
Switching loss vs. Collector current (typ.) Vcc=600V, VgE=±15V, Rg=1Ω, Tj=125°C, 150°C



Collector current: Ic [A]

[INVERTER]

Reverse bias safe operating area (max.) +VGE=15V, -VGE=15V, RG=1 Ω , Tj=150°C



[INVERTER]

Forward Current vs. Forward Voltage (typ.) chip

3000
2500

Tj=25° C

1500

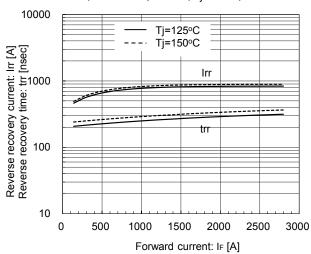
150° C

125° C

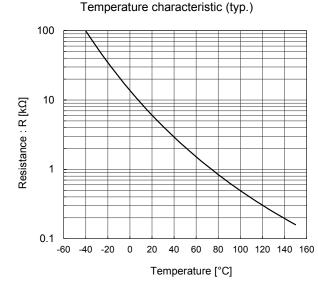
[INVERTER]

Forward on voltage: VF [V]

Reverse Recovery Characteristics (typ.) Vcc=600V, VgE=±15V, Rg=1Ω, Tj=125°C, 150°C

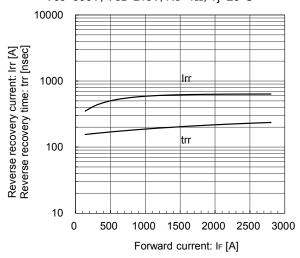


[THERMISTOR]

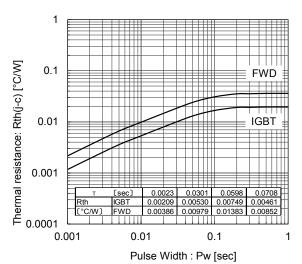


[INVERTER]

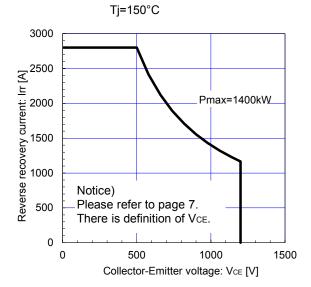
Reverse Recovery Characteristics (typ.) Vcc=600V, $VgE=\pm15V$, $Rg=1\Omega$, $Tj=25^{\circ}C$



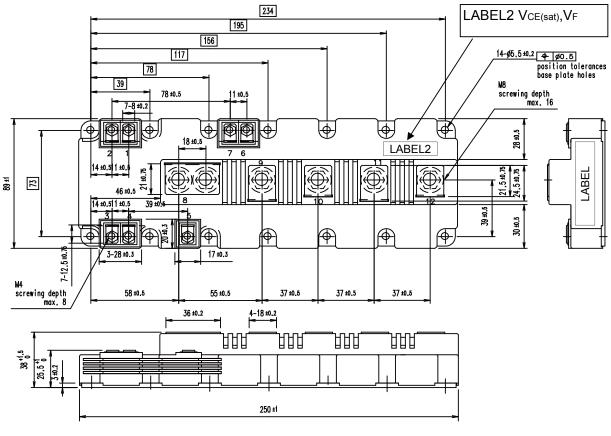
Transient Thermal Resistance (max.)



FWD safe operating area (max.)

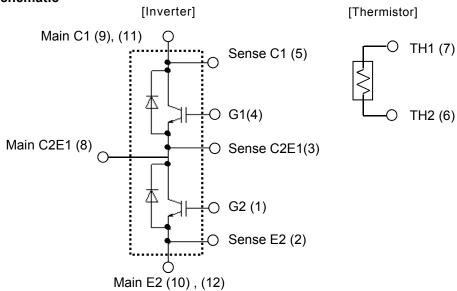


■ Outline Drawings, mm



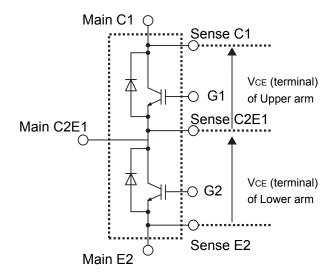
Weight:1250g(typ.)

■ Equivalent Circuit Schematic



http://www.fujielectric.com/products/semiconductor/

■ Definition of on-state voltage at terminal and switching characteristics



Fuji defined VcE value of terminal by using Sense C1 and Sense C2E1 for Upper arm and Sense C2E1 and Sense E2 for Lower arm .

Switching characteristics of VcE also is defined between Sense C1 and Sense C2E1 for Upper arm and Sense C2E1 and Sense E2 for Lower arm .

Please use these terminals whenever measure spike voltage and on-state voltage .

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